

Regular Article

The Effects of Dielectric Coatings on Electron Emission from Tungsten

Ala'a M. Al-Qudah, Shady S. Alnawasreh, Mazen A. Madanat, Oliwia Trzaska¹, Danuta Matykiewicz², Saad S. Alrawshdeh³, Mark J. Hagmann⁴, Marwan S. Mousa*

Department of Physics, Mu'tah University, Al-Karak 61710, Jordan ¹Laboratory of Plastics, Wrocław University of Technology, Wrocław 50371, Poland ²Institute of Materials Technology, Poznan University of Technology, Poznan 61138, Poland ³Department of Mechanical Engineering, Mu'tah University, Al-Karak 61710, Jordan ⁴Department of Electrical and Computer Engineering, University of Utah, Salt Lake City, UT 84112, USA

*Correspondence to: Mousa MS, Tel: +962-79-5659761 Fax: +962-3-2375540 E-mail: mmousa@mutah.edu.jo

Received July 21, 2016 Revised December 2, 2016 Accepted December 5, 2016 Field electron emission measurements were performed on dielectric-coated tungsten emitters, with apex radii in the nanometer and micrometer range, which were prepared by electrochemical etching in NaOH solution. Measurements were performed in a field electron microscopy (FEM) with a base pressure $<10^{-6}$ Pascal (10^{-8} mbar). Four different types of dielectric were used, namely: (1) Clark Electromedical Instruments epoxylite resin, (2) Epidian 6 produced by Ciech Sarzyna S. A., (3) a Radionox solution of colloidal graphite; and (4) Molyslip 2001 E compound (MoS₂ and MoS). Currentvoltage measurements and FEM images were used to investigate the characteristics of these composite emitters, and to assess how the different types of dielectric coating affect the suitability of the composite emitter as a potential electron source.

Key Words: Field electron emitter, Dielectric layers, Composite emitters, Field electron microscope

INTRODUCTION

Field electron emission (FE) is the emission of electrons from the surface of a cathode under the influence of a high applied electrostatic field. This field is typically in the range 3 to 5 V/ nm, for a tungsten emitter with a work function of 4.5 eV (Forbes, 2008; and take the reference field at which the barrier goes below the Fermi level as 14.1 V/nm).

As an electron source, the field emitter is particularly attractive due to its favorable emission properties and simple operating principle. The study of field emitters as potential electron sources for electron-beam instruments started around 1954 (Dyke & Dolan, 1956). The first practical utilization of such sources appeared late in 1968 as a part of a scanning electron microscope (Crewe et al., 1968,1969; Crewe & Wall, 1970). Many experimental FE studies have been carried out on tungsten, lanthanum hexaboride and carbon fiber emitters. From the 1920s onwards, and for a long period thereafter, tungsten was the most widely used material for field emitters. Tungsten brings several benefits due to its favorable properties, such as ready availability in wire form, high melting point of 3,422°C, hardness (strength), low vapor pressure, simplicity of emitter preparation by electrochemical etching, and durability. Techniques for preparing FE cathodes are well developed. Advances in vacuum technology have also been important, because a high-quality vacuum is essential for reliable operation of field emission cathodes.

These developments have enabled the widespread use of FE cathodes (Dyke & Dolan, 1956; Zhu, 2001). Cathode-fabrication technology based on electrolytic etching (Melmed, 1991) has been studied and enhanced. This technology now makes it possible to prepare a cathode tip with a diameter

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of several nanometers. Composite micro-point cathodes have been prepared, with the aims of improving the emission characteristics needed for small bright electron sources, and reducing degradation of the electron emitter due to ion sputtering during emission (hence improving lifetime) (Al-Qudah et al., 2015; Latham & Mousa, 1986; Mousa, 1990; Mousa et al., 1994, 2012; Mousa & Al Share, 1999).

The research reported here continues this work on composite micro-point cathodes. It is based on investigating the current-voltage (I[V]) characteristics, determining the spatial emission current distributions via field electron microscopy (FEM), and noting the gross stability of these electron emission images. Various dielectric coatings have been used in preparing the composite cathodes, in a preliminary attempt to see if the nature of the coating makes any difference.

MATERIALS AND METHODS

The procedures used for coating tungsten emitters in the present work are the same as those described previously (Al-Qudah et al., 2015; Latham & Mousa, 1986). In all cases, the micro-point, nano-apex metallic emitters used were electrolytically etched from 0.1 mm diameter tungsten wires of 99.95% purity (Goodfellow Metals, England), using a 2 M solution of NaOH, and were then ultrasonically cleaned. The coating procedure involved slowly dipping the emitter into resin and then carefully removing it, ensuring that only a thin film remained on its surface. This procedure was repeated 12 times, leading to a coating about 150 to 200 nm thick. The emitter was then carefully transferred to an oven and

subjected to a resin-curing cycle of thirty minutes at 100°C to drive off the solvents, followed by another thirty minutes at 185°C to complete the curing (Al-Qudah et al., 2015; Latham & Mousa, 1986).

The emitters were studied in a FEM pumped with a diffusionpump system having an additional liquid nitrogen trap. Base pressures of $\langle 5 \times 10^{-6}$ Pascal (10^{-8} mbar) have been reached after baking the system at a temperature of 180°C for 12 hours with liquid nitrogen in the trap. In the FEM, the separation between the cathode and the anode was standardized at ~10 mm, and a current-limiting resistor of 100 M Ω was used. The FEM images were recorded by a digital camera placed outside a window of the vacuum system.

For the I(V) measurements, a high-voltage power supply was used to apply a high negative voltage to the cathode. The emission current was measured with a Keithley 485 autoranging pico-ammeter (Madanat et al., 2015). Fig. 1 shows a schematic diagram of the FEM, including the diffusion pump system.

RESULTS

As indicated above, investigations have been carried out for tungsten emitters and different coatings, namely: (1) Clark Electromedical Instruments epoxylite resin (England), (2) Epidian 6 produced by Ciech Sarzyna S.A. (Poland), (3) a Radionox solution of colloidal graphite; and (4) Molyslip 2001 E compound (MoS_2 and MoS). As indicated above, the results presented here are the I(V) characteristics and the related FEM images. We also compare these results with the

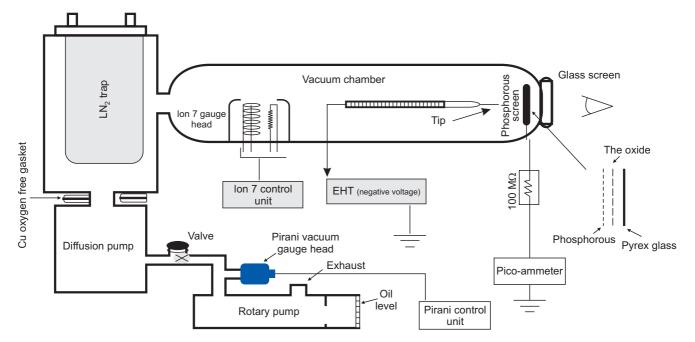


Fig. 1. Schematic diagram of a field electron microscope with a diffusion-pumped vacuum chamber.



equivalent results for the uncoated tungsten microemitters.

Composite Tungsten: Clark Electromedical Instruments Epoxylite Resin Tip

First, we determined the emission characteristics of an uncoated tungsten tip, as shown in Fig. 2. Fig. 3 shows the related FEM images, for selected values of the voltage and related current. In this case, as in all cases below, the ranges of current and voltage used are shown in Table 1 (in this case as part of the data for "Emitter 1").

After coating with Clark Electromedical Instruments epoxylite resin, the voltage applied to the composite emitter was slowly increased until the "switch-on voltage" V_{sw} was reached. At this point the emission current switches on to a "nearly saturated" value called the "switch-on current" I_{sw} (see red marked points in Fig. 4A). In this experiment we found V_{sw} =2,400 V and I_{sw} =1.5 µA. It has already been found in earlier work (Latham and Mousa, 1986) that after switch-on the current increases relatively slowly, so we did not consider it necessary to explore this upper part of the voltage range in the present experiments. Partly, this was a precaution to avoid accidentally destroying the emitter.

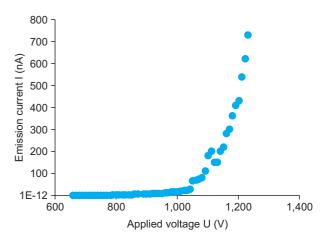


Fig. 2. The current-voltage I(V) characteristics of a tungsten emitter (emitter 1) before coating.

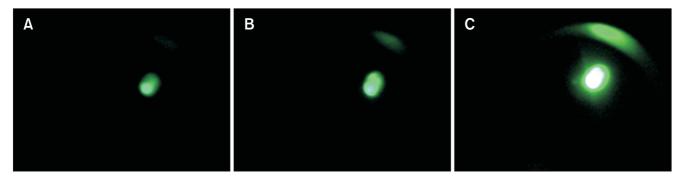


Fig. 3. Field electron emission micrographs of emitter 1 before coating, taken as voltage increases, at the following (*V*, *I*) values. (A) 870 V, 5 nA; (B) 960 V, 11 nA; (C) 1,050 V, 64 nA.

Table 1. Comparison of current-voltage-based data in the four cases* of tungsten micro-point emitters	Table 1. Compariso	n of current-voltage-ba	sed data in the four cas	ses* of tungsten micro	-point emitters
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Duran autor	Emitter 1		Emitter 2		Emitter 3		Emitter 4	
Property	Voltage (V)	Current	Voltage (V)	Current	Voltage (V)	Current	Voltage (V)	Current
Uncoated emitter								
Onset values	650	4.5 pA	390	8 pA	800	76 pA	1,100	66 pA
Upper values	1,230	720 nA	1,000	1.1 µA	1,800	770 nA	2,100	520 nA
Circuit resistance at onset	140 ΤΩ		49 TΩ		11 TΩ		$17 \mathrm{T}\Omega$	
Circuit resistance at upper point	$1.7 \mathrm{G\Omega}$		0.91 GΩ		$2.3 \text{G}\Omega$		$4.0~\mathrm{G}\Omega$	
Resistance ratio (onset/upper point)	84,000		54,000		4,500		4,100	
Coated emitter								
Switch-on values (V_{sw} , I_{sw})	2,400	1.5 µA	6,900	1.2 µA	2,300	5.4 µA	2,500	7.3 µA
First decreasing run - bottom	700	8.8 pA	500	8.3 pA	600	9.1 pA	600	88 pA
Second increasing run - bottom	700	6.7 pA	1,100	11 pA	400	11 pA	500	11 pA
Second increasing run - top	1,900	1.1 μA	2,900	1 µA	1,300	780 nA	1,300	440 nA
Other data								
Post-switch-on circuit resistance	$1.6 \mathrm{G}\Omega$		$5.8 \mathrm{G}\Omega$		$420 \mathrm{M}\Omega$		$340\mathrm{M}\Omega$	
Image quality (coated emitter)	Very good		Medium		Limited		Limited	

*Coated by: (1) Clark Electromedical Instruments epoxylite resin; (2) Epidian 6 epoxy resin (based on Bisphenol A); (3) A Radianox solution of colloidal graphite; (4) Molyslip 2001 EE compound (MoS2 and MoS).



Starting from the switch-on voltage, the voltage was then decreased: the blue marked points in Fig. 4A shows I(V) values recorded during this "decreasing" sequence. FEM images were observed during the process of decreasing the voltage, and a set of micrographs were recorded, as shown in Fig. 5. An interval of 15 minutes was allowed between each photograph. What Fig. 4A and 5 clearly demonstrate is that, certainly at a gross level, the emission current distribution was relatively stable, both over time and over a significant range of voltage.

After the voltage had been decreased to zero, it was then increased again up to close to the original switch-on voltage. The resulting I(V) plot is shown in Fig. 4B. In this "postswitch-on" case, the I(V) plot qualitatively resembles that found in the previous decreasing sequence, rather than the plot found in the first increasing sequence, although numerical values are not exactly the same. This shows clearly that the switch-on event has induced some permanent or long-time-scale change in the coating. This change is thought

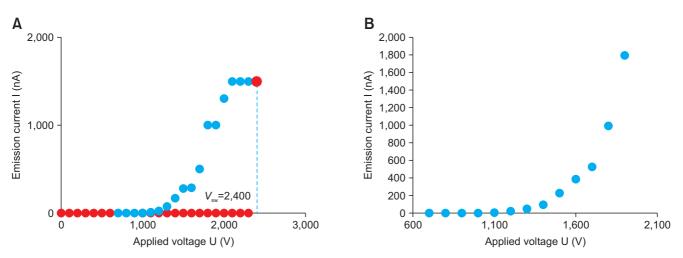


Fig. 4. *I*(*V*) characteristics of emitter 1 after coating with Clark Electromedical Instruments epoxylite resin. (A) The red dots show the first voltage-increasing (*V*-increasing) data-set, up to switch-on at *V*_{sw}=2,400 V, *I*_{sw}=1.5 µA; the blue dots show the first *V*-decreasing data-set. (B) The second *V*-increasing data-set.

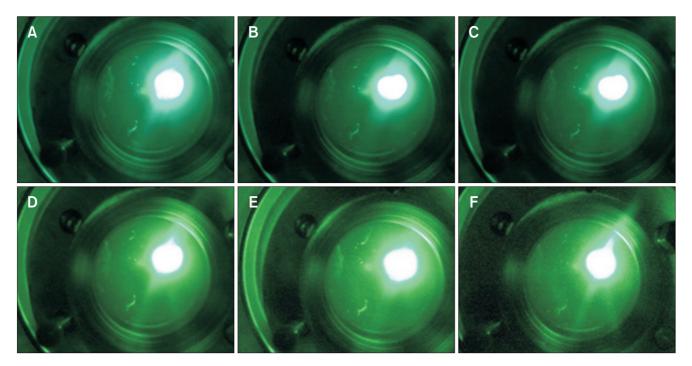


Fig. 5. Field electron emission micrographs of coated emitter 1 taken during the first voltage-decreasing sequence, at the following voltage and current values. (A) 2,400 V, 1.5 μ A; (B) 2,300 V, 1.5 μ A; (C) 2,200 V, 1.5 μ A; (D) 1,900 V, 1.3 μ A; (E) 1,800 V, 1 μ A; (F) 1,700 V, 1 μ A. The time separation between each two consecutive images is 15 minutes.



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to be associated with the formation of a conducting channel through the coating, as first suggested by Latham and Mousa (1986), but the exact nature of the channel remains unclear.

Other Composite Emitters

We then carried out procedurally identical sets of experiments with the other three coatings. Results were qualitatively similar to those described above for the epoxylite resin coating. A switch-on phenomenon occurred in all cases, and the FEM images after switch-on were relatively stable over a range of times and voltages. However, quantitative details of the I(V)characteristics and the details of the FEM images varied for the four differently coated emitters.

The resulting data are presented in the following way. Fig. 6, 7, and 8 show the I(V) characteristics for, respectively, emitters 2, 3 and 4. The left-hand plot shows the first voltage-

increasing (*V*-increasing; red dots) and *V*-decreasing (blue dots) sequences; the right-hand plot shows the second *V*-increasing sequence. Fig. 9 then shows "before coating" and "after coating" images (vertically arranged pairs) for each of emitters 2, 3 and 4 (arranged left to right).

Table 1 shows relevant voltage and current ranges. It also shows values of the measured *circuit resistance* R_m defined by

$$R_{\rm m} = V/I. \tag{1}$$

Note that R_m is **not** the emission resistance R_e associated with the emitter by itself (Forbes et al., 2015) but is a particular value of the total (voltage-dependent) resistance R_m seen by the voltage supply, for given physical circumstances of the circuit. For the uncoated emitters, Table 1 shows R_m -values at onset and at the top of the voltage range used, and also

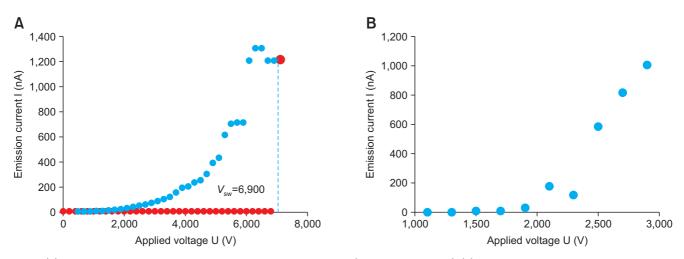


Fig. 6. I(V) characteristics of emitter 2 after coating with Epidian 6 epoxy resin (based on bisphenol A). (A) The red dots show the first voltage-increasing (*V*-increasing) data-set, up to switch-on at V_{sw} =6,900 V, I_{sw} =1.2 μ A; the blue dots show the first *V*-decreasing data-set. (B) The second *V*-increasing data-set.

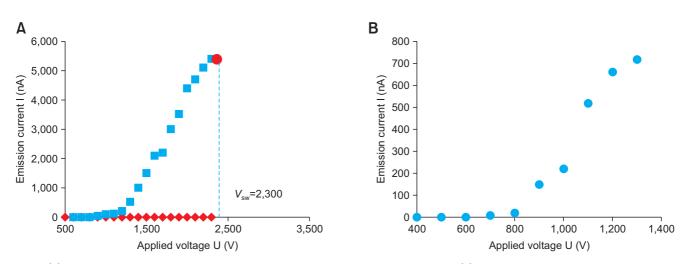


Fig. 7. I(V) characteristics of emitter 3 after coating with a Radianox compound of colloidal graphite. (A) The red dots show the first voltage-increasing (*V*-increasing) data-set, up to switch-on at V_{sw} =2,500 V, I_{sw} =5.4 μ A; the blue dots show the first *V*-decreasing data-set. (B) The second *V*-increasing data-set.



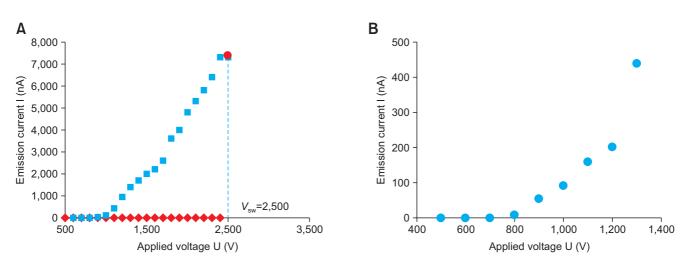


Fig. 8. I(V) characteristics of emitter 4 after coating with Molyslip 2001 EE compound (MoS2 and MoS). (A) The red dots show the first voltage-increasing (*V*-increasing) data-set, up to switch-on at V_{sw} =2,500 V, I_{sw} =7.3 μ A; the blue dots show the first *V*-decreasing data-set. (B) The second *V*-increasing data-set.

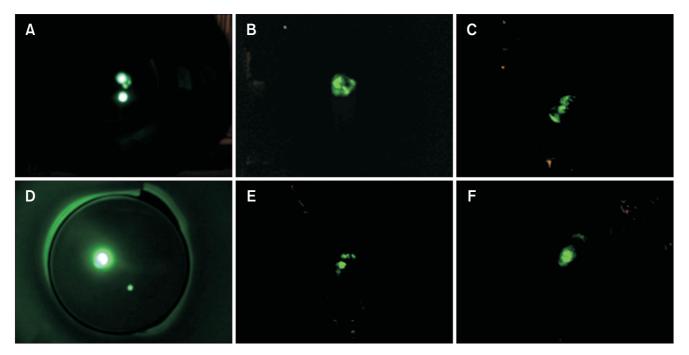


Fig. 9. For each of emitters 2, 3 and 4, in sequence left to right, this figure shows typical FEM images before (A-C), and after (D-F) coating. For each emitter, the "before" and "after" images are aligned vertically. Images were taken at the following data points: (A) 1,000 V, 1.1 μA; (B) 1,800 V, 0.8 μA; (C) 2,100 V, 0.52 μA; (D) 6,900 V, 1.2 μA; (E) 2,300 V, 5.4 μA; (F) 2500 V, 7.3 μA.

the ratio of these values. For the coated emitters, the circuit resistance immediately post switch-on is shown. The lowest section of the Table 1 also records a qualitative assessment of the usefulness of the observed emission distribution for the purpose of developing electron sources.

DISCUSSION AND CONCLUSIONS

The most important finding from this work is that the switch-

on phenomenon occurs with all of the four different dielectric coatings used. Whilst this is not entirely surprising, it is something that needed to be investigated. What this means is that the *basic* explanation of the phenomenon needs to be relatively general, and not specific to particular individual materials. The hypothesis of conducting-channel formation is a general explanation of this kind. Of course, other hypotheses may emerge. Another important finding is that, at the gross level, the emission images are in all cases relatively stable over



a range of times and applied voltages. This is a necessary requirement if an emitter is to be used as an electron source.

As regards the more detailed suitability of these emitters as potential electron sources, the data in Table 1 exhibit conflicting trends. The lower values of the "post-switch-on circuit resistance" R_{sw} for emitters 3 and 4 appears to suggest that the related coatings would allow greater current to be achieved at lower voltages. On the other hand, the FEM images suggest that emitter 1 (and, to a lesser extent, emitter 2) would be more suitable, because the emission occupies larger angle in the field of view. The particularly large values of V_{sw} and R_{sw} for emitter 2 could arise because the coating in question (Epidian 6) solidifies to form a very hard layer on the apex of the underlying tungsten emitter; this could perhaps have an advantage in prolonging emitter lifetime.

Another feature of Table 1 is that the circuit-resistance data for emitters 3 and 4, before coating, look appreciably different from the data for emitters 1 and 2, before coating. This suggests the possibility that the properties (maybe shape and size) of the uncoated tungsten emitters may also be playing a role.

Clearly, further investigation of composite emitters would be worthwhile. In our view, the most obvious next step would be to investigate the properties of a significant number of emitters of type 1, to see how reproducible are the properties we have found here for a single emitter of this type. In particular, the FEM images found here for a type 1 coated emitter are somewhat similar to, but not identical with, the images found previously for an emitter of this type (Al-Qudah et al., 2015), so obviously some variability is to be expected. It would also be helpful to know whether the shape and size of the uncoated tungsten emitter has any significant influence on coated-emitter results, and if so then what influence.

In summary, we have made a preliminary investigation of the emission properties of tungsten micro-point emitters coated with four different types of dielectric coating, and have found that a "switch-on" phenomenon occurs in all cases, and that the post-switch-on emission images are (at the gross level) stable over a range of times and voltage values. We have selected the emitter type "tungsten coated with Clark Electromedical Instruments epoxylite resin" as the best candidate for further investigations.

CONFLICT OF INTEREST

No potential conflict of interest relevant to this article was reported.

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